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April 2015

FGH60N60SFDTU_F085 600 V, 60 A Field Stop IGBT

Features

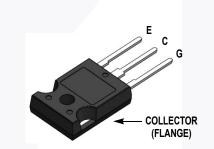
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} = 2.2 V @ I_C = 60 A
- High Input Impedance
- Fast Switching
- RoHS Compliant
- · Qualified to Automotive Requirements of AEC-Q101

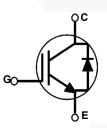
Applications

- · Automotive chargers, Converters, High Voltage Auxiliaries
- · Inverters, PFC, UPS

General Description

Using Novel Field Stop IGBT Technology, Fairchild's new series of Field Stop IGBTs offer the optimum performance for Automotive Chargers, Inverter, and other applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

| Symbol | Description | | Ratings | Unit |
|---------------------|--|---------------------------------------|-------------|------|
| V _{CES} | Collector to Emitter Voltage | | 600 | V |
| V | Gate to Emitter Voltage | ±20 | V | |
| V _{GES} | Transient Gate-to-Emitter Voltage | ±30 | v | |
| I _C | Collector Current | @ T _C = 25°C | 120 | A |
| 10 | Collector Current | @ T _C = 100 ^o C | 60 | A |
| I _{CM (1)} | Pulsed Collector Current | @ T _C = 25°C | 180 | A |
| P _D | Maximum Power Dissipation | @ T _C = 25 ^o C | 378 | W |
| . D | Maximum Power Dissipation | @ T _C = 100°C | 151 | W |
| TJ | Operating Junction Temperature | | -55 to +150 | °C |
| T _{stg} | Storage Temperature Range | | -55 to +150 | °C |
| TL | Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds | 300 | °C | |

Notes:

1: Repetitive test, Pulse width limited by max. juntion temperature

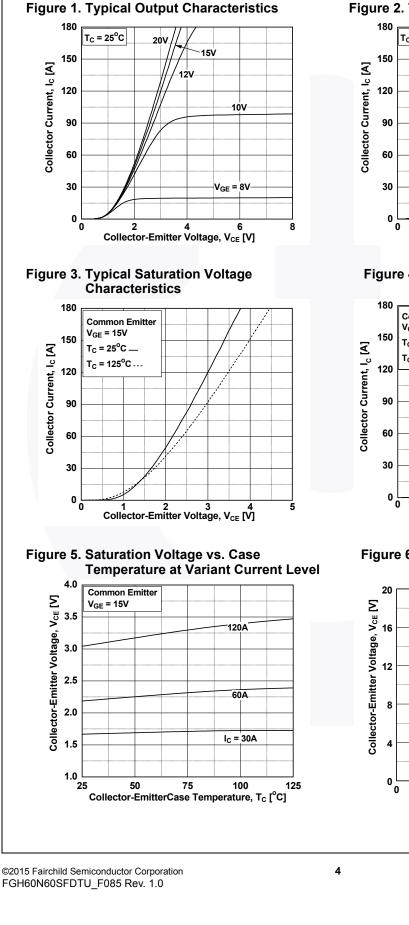
Thermal Characteristics

| Symbol | Parameter | Тур. | Unit |
|------------------------|---|------|------|
| $R_{\theta JC}(IGBT)$ | Thermal Resistance, Junction to Case | 0.33 | °C/W |
| $R_{\theta JC}(Diode)$ | Thermal Resistance, Junction to Case | 1.1 | °C/W |
| $R_{	ext{	heta}JA}$ | Thermal Resistance, Junction to Ambient | 40 | °C/W |

| Part I | Number | Top Mark | Pack | cage | Packing Method | Reel Size | Tape \ | Width | Quantity |
|-------------------------------------|---|-----------------------|-------|--|---|-----------|--------|-------|----------|
| FGH60N60 | GH60N60SFDTU_F085 FGH60N60SFD TC | | TO- | -247 Tube | | N/A | N/A | | 30 |
| Electric | al Charac | teristics of t | he IG | вт | T _C = 25°C unless otherwise not | ed | | | |
| Symbol | F | Parameter | | | Test Conditions | Min. | Тур. | Max | Unit |
| Off Charac | teristics | | | | | | | | |
| BV _{CES} | Collector to Er | nitter Breakdown Vo | ltage | V _{GE} = | 0 V, I _C = 250 μA | 600 | - | - | V |
| ΔBV_{CES} / ΔT_J | Temperature (Voltage | Coefficient of Breako | down | $V_{GE} = 0 \text{ V}, \text{ I}_{C} = 250 \mu\text{A}$ $V_{CE} = V_{CES}, V_{GE} = 0 \text{V}$ | | - | 0.4 | - | V/ºC |
| I _{CES} | Collector Cut- | Off Current | | | | - | _ | 250 | μA |
| I _{GES} | G-E Leakage | Current | | $V_{GE} = V_{GES}, V_{CE} = 0 V$ | | - | - | ±400 | nA |
| | | | | _ | | | | 1 | I |
| On Charac | 1 | | | | | | | | |
| V _{GE(th)} | G-E Threshold Voltage | | | - | 60 μA, V _{CE} = V _{GE} | 4.0 | 5.1 | 6.6 | V |
| | | – | - | A, V _{GE} = 15 V | - | 2.2 | 2.9 | V | |
| V _{CE(sat)} | Collector to Emitter Saturation Voltage | | - | I _C = 60 T _C = 1 | A, V _{GE} = 15 V, 25 ^o C | - | 2.4 | - | V |
| Dynamic C | haracteristics | | | | | | | | |
| C _{ies} | Input Capacita | | | V _{CE} = 30 V, V _{GE} = 0 V, f = 1 MHz | | - | 2940 | - | pF |
| C _{oes} | Output Capac | | | | | - | 310 | - | pF |
| C _{res} | Reverse Trans | sfer Capacitance | | | | - | 100 | - | pF |
| Switching | Characteristic | s | | | | | | | |
| t _{d(on)} | Turn-On Delay | y Time | | | | - | 26 | - | ns |
| t _r | Rise Time | | | $V_{CC} = 400 \text{ V}, \text{ I}_{C} = 60 \text{ A},$ R _G = 5 Ω, V _{GE} = 15 V, Inductive Load, T _C = 25 ^o C | | - | 54 | - | ns |
| t _{d(off)} | Turn-Off Delay | y Time | | | | - | 134 | - | ns |
| t _f | Fall Time | | | | | - | 18 | 62 | ns |
| Eon | Turn-On Swite | ching Loss | | | | - | 1.97 | - | mJ |
| E _{off} | Turn-Off Swite | ching Loss | | | | / | 0.57 | - | mJ |
| E _{ts} | Total Switchin | g Loss | | | | - | 2.54 | - | mJ |
| t _{d(on)} | Turn-On Delay | y Time | | | | - | 26 | - | ns |
| t _r | Rise Time | | | V _{CC} = 400 V, I _C = 60 A, | | - | 50 | - | ns |
| t _{d(off)} | Turn-Off Delay | y Time | | | | - | 142 | - | ns |
| t _f | Fall Time | | | R _G = 5 Ω, V _{GE} = 15 V, | | - | 24 | - | ns |
| Eon | Turn-On Swite | ching Loss | | Inductive Load, T _C = 125 ^o C | | - | 2.5 | - | mJ |
| E _{off} | Turn-Off Swite | ching Loss | | | | - | 0.8 | - | mJ |
| E _{ts} | Total Switchin | g Loss | | | | - | 3.2 | - | mJ |
| Qg | Total Gate Ch | arge | | | | - | 188 | - | nC |
| Q _{ge} | Gate to Emitte | er Charge | | $V_{CE} = $ | 400 V, I _C = 60 A, | - | 21 | - | nC |
| Q _{gc} | Gate to Collec | - | | V _{GE} = 15 V | | _ | 98 | - | nC |

FGH60N60SFDTU_F085 — 600 V, 60 A Field Stop IGBT

| Symbol | Parameter | Test Conditions | | Min. | Тур. | Max | Unit |
|-----------------|-------------------------------|---|------------------------------------|------|------|-----|------|
| V _{FM} | Diode Forward Voltage | I _F = 30 A | T _C = 25°C | - | 1.9 | 2.6 | V |
| * FIM | | 1F 0077 | T _C = 125°C | - | 1.7 | - | |
| t | Diode Reverse Recovery Time | I _F = 30 A, di _F /dt = 200 A/μs | T _C = 25°C | - | 55 | - | ns |
| ۲r | | | T _C = 125°C | - | 204 | - | |
| Q _{rr} | Diode Reverse Recovery Charge | ης – 30 Α, αιείαι – 200 Αίμα | T _C = 25 ^o C | - | 125 | - | nC |
| | | | T _C = 125°C | - | 895 | - | |



Typical Performance Characteristics

Figure 2. Typical Output Characteristics

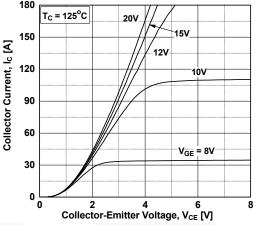
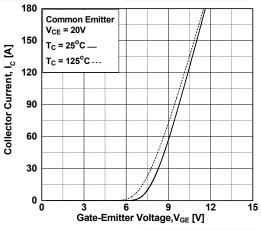
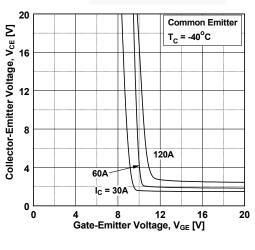


Figure 4. Transfer Characteristics







Common Emitter

16

300V

200V

150

200

20

T_c = 125^oC

12

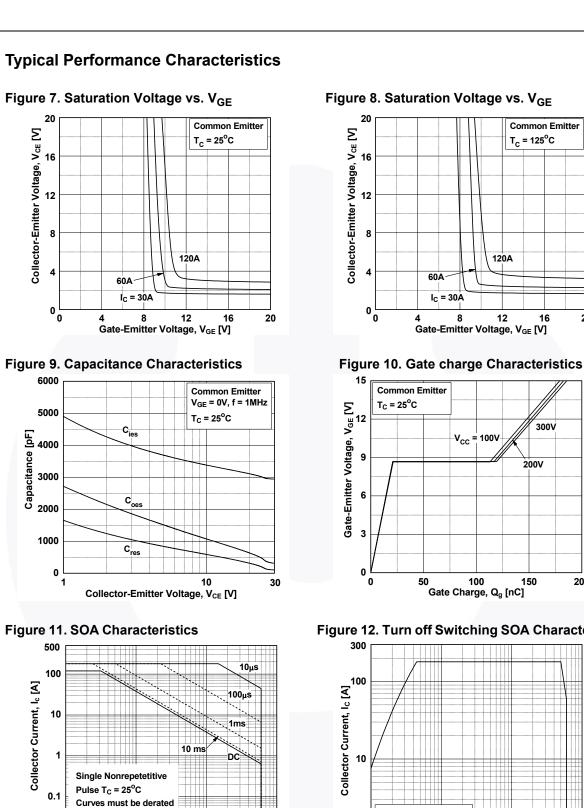
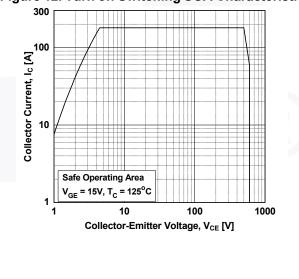


Figure 12. Turn off Switching SOA Characteristics



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linearly with increase in temperature

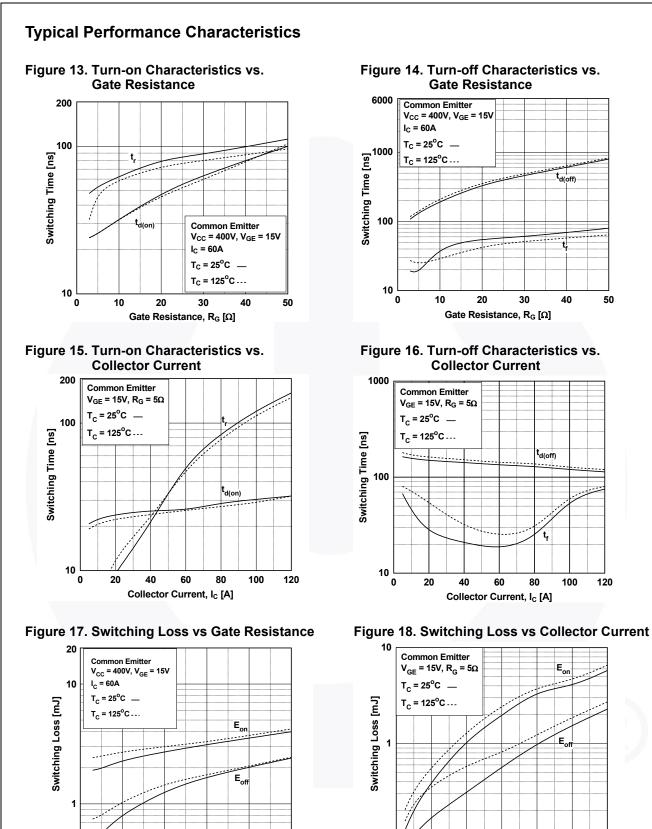
10

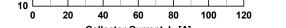
Collector-Emitter Voltage, V_{CE} [V]

100

5

1000





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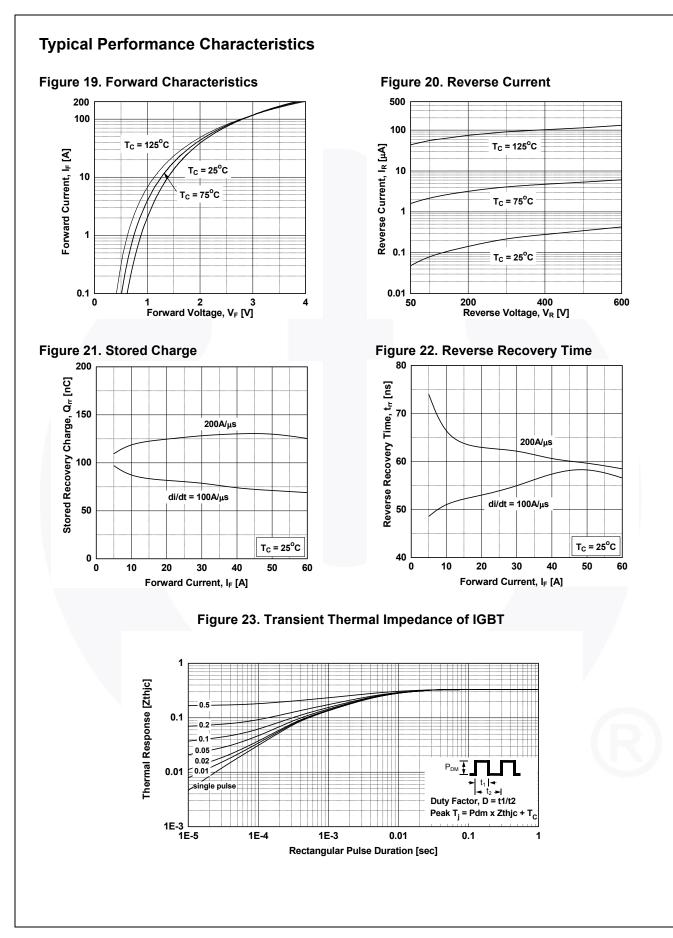
Gate Resistance, R_G [Ω]

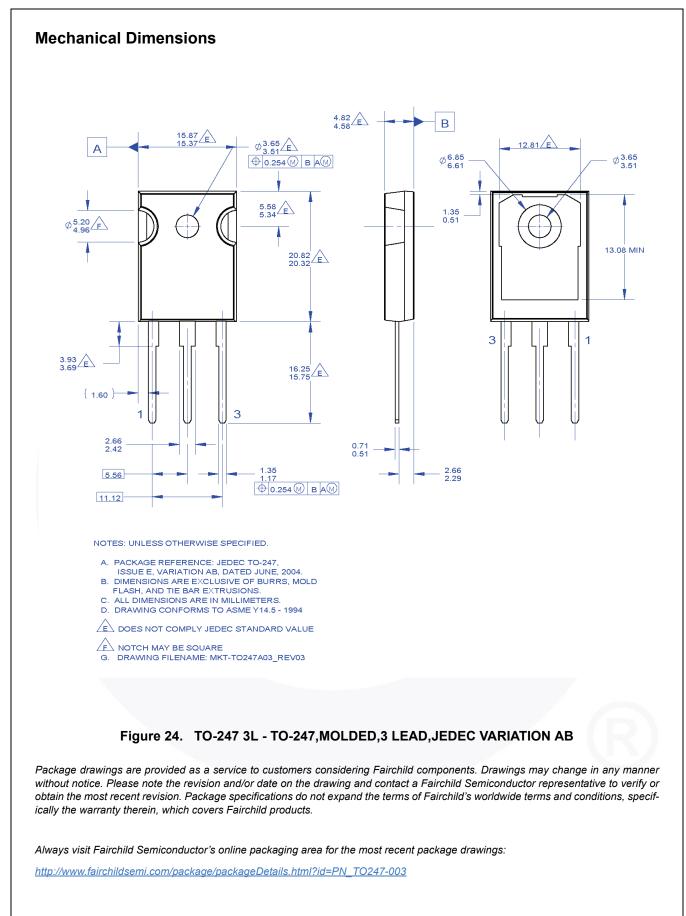
Collector Current, Ic [A]

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